





SN74LV157A

SCLS397G - APRIL 1998 - REVISED MARCH 2023

# SN74LV157A Quadruple 2-Line to 1-Line Data Selectors/Multiplexers

### 1 Features

**TEXAS** 

- Operates 2 V to 5.5 V V<sub>CC</sub>
- Inputs accept voltages to 5.5 V •
- Max t<sub>pd</sub> of 7.5 ns at 5 V

**INSTRUMENTS** 

- Typical  $V_{OLP}$  (Output Ground Bounce) < 0.8 V at ٠  $V_{CC}$ ,  $T_A = 25^{\circ}C$
- Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot) > 2 V at  $V_{CC}$ ,  $T_A = 25^{\circ}C$
- Latch-up performance exceeds 100 mA per JESD 78, Class II

## 2 Applications

- Servers
- LED Displays
- **Network Switches**
- **Telecom Infrastructure** •
- Motor Drivers
- I/O Expanders

## **3 Description**

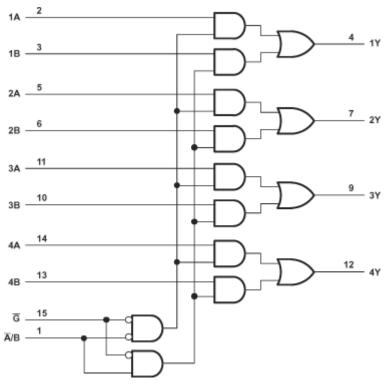
The 'LV157A devices are quadruple 2-line to 1-line data selectors/multiplexers designed for

2 V to 5.5 V  $V_{CC}$  operation.

Package	Information <sup>(1)</sup>
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PART NUMBER	PACKAGE	BODY SIZE (NOM)			
	DB (SSOP, 16)	6.2 mm × 5.3 mm			
	DGV (TVSOP, 16)	3.6 mm × 4.4 mm			
SN74LV157A	DW ( SOIC,16)	10.3 mm × 7.5 mm			
	NS (SOP, 16)	10.3 mm × 5.3 mm			
	PW (TSSOP, 16)	5 mm × 4.4 mm			

For all available packages, see the orderable addendum at (1) the end of the data sheet.



Logic Diagram (Positive Logic)





Page

## **Table of Contents**

1 Features1	7 Parameter Measurement Information	8
2 Applications1	8 Detailed Description	9
3 Description1	8.1 Overview	9
4 Revision History	8.2 Functional Block Diagram	9
5 Pin Configuration and Functions	8.3 Device Functional Modes	
6 Specifications	9 Application and Implementation	10
6.1 Absolute Maximum Ratings4	9.1 Power Supply Recommendations	10
6.2 ESD Ratings4	9.2 Layout.	10
6.3 Recommended Operating Conditions5	10 Device and Documentation Support	11
6.4 Thermal Information5	10.1 Documentation Support	11
6.5 Electrical Characteristics5	10.2 Receiving Notification of Documentation Updates	11
6.6 Switching Characteristics, V <sub>CC</sub> = 2.5 V ± 0.2 V6	10.3 Support Resources	11
6.7 Switching Characteristics, V <sub>CC</sub> = 3.3 V ± 0.3 V6	10.4 Electrostatic Discharge Caution	11
6.8 Switching Characteristics, V <sub>CC</sub> = 5 V ± 0.5 V6	10.5 Glossary	11
6.9 Noise Characteristics7	11 Mechanical, Packaging, and Orderable	
6.10 Operating Characteristics7	Information	12

## **4 Revision History**

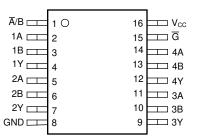
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision F (April 1998) to Revision G (March 2023)

•	Added Applications, Package Information table, Pin Functions table, ESD Ratings table, Thermal Information
	table, Device Functional Modes, Application and Implementation section, Power Supply Recommendations
	section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and
	Orderable Information section



## **5** Pin Configuration and Functions



#### Figure 5-1. D, DB, DGV, NS, or PW Package (Top View)

Р	IN	I/O <sup>(1)</sup>	DESCRIPTION
NO.	NAME	1/0(*)	DESCRIPTION
1	Ā/B	I	Address select
2	1A	I	Channel 1, data input A
3	1B	I	Channel 1, data input B
4	1Y	I	Channel 1, data output
5	2A	0	Channel 2, data input A
6	2B	0	Channel 2, data input B
7	2Y	I	Channel 2, data output
8	GND	_	Ground
9	3Y	I	Channel 3, data output
10	3B	I	Channel 3, data input B
11	3A	I	Channel 3, data input A
12	4Y	I	Channel 4, data output
13	4B	I	Channel 4, data input B
14	4A	I	Channel 4, data input A
15	G	I	Output strobe, active low
16	V <sub>CC</sub>	_	Positive supply

#### Table 5-1. Pin Functions



## 6 Specifications 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	7	V
VI	Input voltage <sup>1</sup>			7	V
Vo	Output voltage range applied in high or low state <sup>1 (1)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
Vo	Output voltage range applied in power-off state <sup>1</sup>		-0.5	7	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
lo	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature		-65	150	°C

(1) This value is limited to 5.5 V maximum.

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
		Human-Body Model (A114-A) <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	V <sub>(ESD)</sub> Electrostatic discharge	Machine Model (A115-A)	±200	V
		Charged-Device Model (C101) <sup>(2)</sup>	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### **6.3 Recommended Operating Conditions**

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	V
		$V_{CC} = 2 V$	1.5		
		$V_{CC}$ = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> × 0.7		V
	High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.7		
		V <sub>CC</sub> = 2 V		0.5	
		V <sub>CC</sub> = 2.3 V to 2.7 V		V <sub>CC</sub> × 0.3	V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		V <sub>CC</sub> × 0.3	
		V <sub>CC</sub> = 4.5 V to 5.5 V		V <sub>CC</sub> × 0.3	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	$V_{CC}$	V
		$V_{CC} = 2 V$		- 50	μA
lau	High-level output current	$V_{CC}$ = 2.3 V to 2.7 V		-2	
ЮН	Input voltage Output voltage High-level output current	V <sub>CC</sub> = 3 V to 3.6 V		6	mA
V <sub>IL</sub> La V <sub>I</sub> In V <sub>O</sub> O I <sub>OH</sub> H I <sub>OL</sub> La Δt/Δv In		V <sub>CC</sub> = 4.5 V to 5.5 V		- 12	
		V <sub>CC</sub> = 2 V		50	μA
		$V_{CC}$ = 2.3 V to 2.7 V		2	
OL		V <sub>CC</sub> = 3 V to 3.6 V		6	mA
		V <sub>CC</sub> = 4.5 V to 5.5 V		12	
		V <sub>CC</sub> = 2.3 V to 2.7 V	0	200	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 3 V to 3.6 V	0	100	ns/V
		$V_{CC}$ = 4.5 V to 5.5 V	0	20	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

## 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>			SN74L	V157A			
		THERMAL METRIC <sup>(1)</sup> D DB		DGV	NS	PW	UNIT
		16 PINS	16 PINS	16 PINS	16 PINS	16 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	73	82	120	64	108	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

### **6.5 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
	I <sub>OH</sub> = -50 μA	2 V to 5.5 V	V <sub>CC</sub> -0.1			
Maria	I <sub>OH</sub> = -2 mA	2.3 V	2			V
V <sub>OH</sub>	I <sub>OH</sub> = -6 mA	3 V	2.48			v
	I <sub>OH</sub> = −12 mA	4.5 V	3.8			



over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP MAX	UNIT
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V	0.1	
	I <sub>OL</sub> = 2 mA	2.3 V	0.4	v
V <sub>OL</sub>	I <sub>OL</sub> = 6 mA	3 V	0.44	V
	I <sub>OL</sub> = 12 mA	4.5 V	0.55	
l <sub>l</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V	± 1	μA
I <sub>CC</sub>	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V	20	μA
I <sub>off</sub>	$V_{\rm I}$ or $V_{\rm O}$ = 0 to 5.5 V	0	5	μA
Ci	$V_{I} = V_{CC}$ or GND	3.3 V	1.7	pF

### 6.6 Switching Characteristics, $V_{CC}$ = 2.5 V ± 0.2 V

over recommended operating free-air temperature range,  $V_{CC}$  = 2.5 V ± 0.2 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то		TA	A = 25°C		SN74LV	'157A	UNIT
PARAMETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	UNIT
A or B         Y           Ā/B         Y           G         Y	A or B	Y			7.4 <sup>1</sup>	15.9 <sup>1</sup>	1	19.5	
	C <sup>L</sup> = 15 pF		7.9 <sup>1</sup>	19.4 <sup>1</sup>	1	23.5	ns		
	G	Y			7.8 <sup>1</sup>	19.8 <sup>1</sup>	1	24	
	A or B	Y			9.4	18.8	1	22	
t <sub>pd</sub>	Ā	Y	C <sub>L</sub> = 50 pF		10.8	22.3	1	26	ns
	G	Y			9.6	22.7	1	26.5	

1. On products compliant to MIL-PRF-38535, this parameter is not production tested.

#### 6.7 Switching Characteristics, $V_{CC}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range,  $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM TO	то		T/	A = 25°C		SN74LV	157A	UNIT
FARAMETER	(INPUT)	(OUTPUT)		MIN	ТҮР	MAX	MIN	MAX	UNIT
	A or B	Y			5.2 <sup>1</sup>	9.7 <sup>1</sup>	1	11.5	
t <sub>pd</sub>	Ā/B	Y	C <sup>L</sup> = 15 pF		5.8 <sup>1</sup>	13.2 <sup>1</sup>	1	15.5	ns
	G	Y			5.5 <sup>1</sup>	13.6 <sup>1</sup>	1	16	
	A or B	Y			6.7	13.2	1	15	
t <sub>pd</sub>	Ā	Y	C <sub>L</sub> = 50 pF		7.6	16.7	1	19	ns
	G	Y			7	17.1	1	19.5	

1. On products compliant to MIL-PRF-38535, this parameter is not production tested.

#### 6.8 Switching Characteristics, V<sub>CC</sub> = 5 V ± 0.5 V

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD CAPACITANCE	TA = 25°C			SN74LV	157A	UNIT
	(INPUT) (OUTPUT)	LOAD CAFACITANCE	MIN	TYP	MAX	MIN	MAX		
	A or B Y		·	3.6 <sup>1</sup>	6.4 <sup>1</sup>	1	7.5		
t <sub>pd</sub>	Ā/B	Y	C <sup>L</sup> = 15 pF	·	4.1 <sup>1</sup>	8.1 <sup>1</sup>	1	9.5	ns
μα	G	Y		·	3.8 <sup>1</sup>	8.6 <sup>1</sup>	1	10	



over recommended operating free-air temperature range,  $V_{CC} = 5 V \pm 0.5 V$  (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM TO		LOAD CAPACITANCE	TA	= 25°C		SN74LV	'157A	UNIT
FARAMETER	(INPUT) (OUTPUT	(OUTPUT)	LOAD CAFACITANCE	MIN	TYP	MAX	MIN	MAX	
	A or B	Y			4.8	8.4	1	9.5	
t <sub>pd</sub>	Ā	Y	C <sub>L</sub> = 50 pF		5.4	10.1	1	11.5	ns
	G	Y			5	10.6	1	12	

1. On products compliant to MIL-PRF-38535, this parameter is not production tested.

#### **6.9 Noise Characteristics**

 $V_{CC}$  = 3.3 V,  $C_L$  = 50 pF,  $T_A$  = 25°C<sup>(1)</sup>

	PARAMETER	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.3	0.8	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		- 0.1	-0.8	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		3.2		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.31			V
V <sub>IL(D)</sub>	Low-level dynamic input voltage			0.99	V

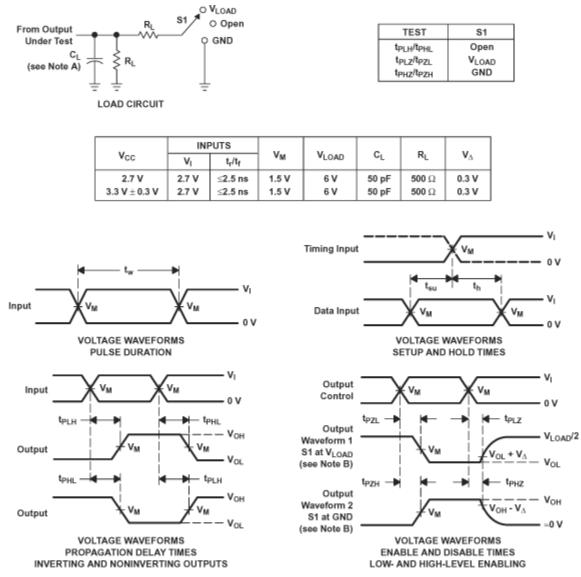
(1) Characteristics are for surface-mount packages only.

### 6.10 Operating Characteristics

T<sub>A</sub> = 25°C

PARAMETER		TES		V <sub>cc</sub>	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	C <sub>L</sub> = 50 pF	f = 10 MHz	3.3 V 5 V	12.1 13.1	pF

### **7 Parameter Measurement Information**



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
   C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.



### 8 Detailed Description

### 8.1 Overview

The 'LV157A devices contain inverters and drivers to supply full data selection to the four output gates. A separate strobe ( $\overline{G}$ ) input is provided. A 4-bit word is selected from one of two sources and is routed to the four outputs. The 'LV157A devices present true data.

### 8.2 Functional Block Diagram

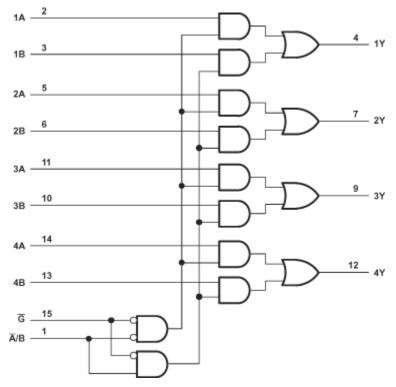


Figure 8-1. Logic Diagram (Positive Logic)

### 8.3 Device Functional Modes

	Table 8-1. Function Table											
INPU	ITS <sup>(1)</sup>	DA	TA									
G	SELECT Ā/B	Α	В	Ουτρυτ Υ								
Н	Х	Х	Х	L								
L	L	L	Х	L								
L	L	Н	Х	Н								
L	Н	Х	L	L								
L	Н	Х	Н	н								

(1) H = High Voltage Level, L = Low Voltage Level, X = Do not Care, Z = High Impedance



### 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### 9.1 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in Section 6.3.

Each V<sub>CC</sub> terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1  $\mu$ F capacitor is recommended. If there are multiple V<sub>CC</sub> terminals then 0.01  $\mu$ F or 0.022  $\mu$ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1  $\mu$ F and 1.0  $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

#### 9.2 Layout

#### 9.2.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or VCC, whichever makes more sense for the logic function or is more convenient.

#### 9.2.1.1 Layout Example

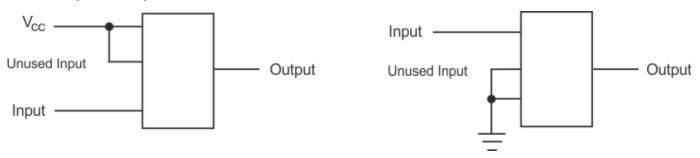


Figure 9-1. Layout Diagram

### **10 Device and Documentation Support**

#### **10.1 Documentation Support**

#### 10.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY							
SN74LV157A	Click here	Click here	Click here	Click here	Click here							

Table 10.1 Deleted Links

#### **10.2 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **10.3 Support Resources**

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### Trademarks

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#### **10.4 Electrostatic Discharge Caution**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.



## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(-)		-			(-)	(6)	(-)		()	
SN74LV157AD	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples
SN74LV157ADBR	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples
SN74LV157ADGVR	ACTIVE	TVSOP	DGV	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples
SN74LV157ADR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples
SN74LV157ANSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV157A	Samples
SN74LV157APW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples
SN74LV157APWG4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples
SN74LV157APWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV157A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



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## PACKAGE OPTION ADDENDUM

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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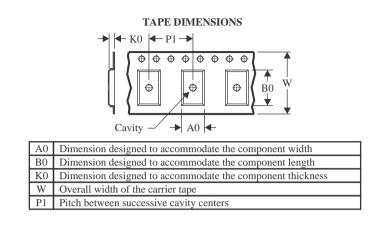


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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal		r							r			. <u> </u>
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV157ADBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV157ADGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV157ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74LV157ANSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LV157APWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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# PACKAGE MATERIALS INFORMATION

13-Mar-2023



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV157ADBR	SSOP	DB	16	2000	356.0	356.0	35.0
SN74LV157ADGVR	TVSOP	DGV	16	2000	356.0	356.0	35.0
SN74LV157ADR	SOIC	D	16	2500	340.5	336.1	32.0
SN74LV157ANSR	SO	NS	16	2000	356.0	356.0	35.0
SN74LV157APWR	TSSOP	PW	16	2000	356.0	356.0	35.0

### TEXAS INSTRUMENTS

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### TUBE



## - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74LV157AD	D	SOIC	16	40	507	8	3940	4.32
SN74LV157APW	PW	TSSOP	16	90	530	10.2	3600	3.5
SN74LV157APWG4	PW	TSSOP	16	90	530	10.2	3600	3.5

# **NS0016A**



## **PACKAGE OUTLINE**

SOP - 2.00 mm max height

SOP



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- Per ASME Y14.5M.
   This drawing is subject to change without notice.
   This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



# NS0016A

# **EXAMPLE BOARD LAYOUT**

## SOP - 2.00 mm max height

SOP



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# NS0016A

# **EXAMPLE STENCIL DESIGN**

## SOP - 2.00 mm max height

SOP



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

# D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# **PW0016A**



# **PACKAGE OUTLINE**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



# PW0016A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# PW0016A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

# **DB0016A**



# **PACKAGE OUTLINE**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-150.



# DB0016A

# **EXAMPLE BOARD LAYOUT**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

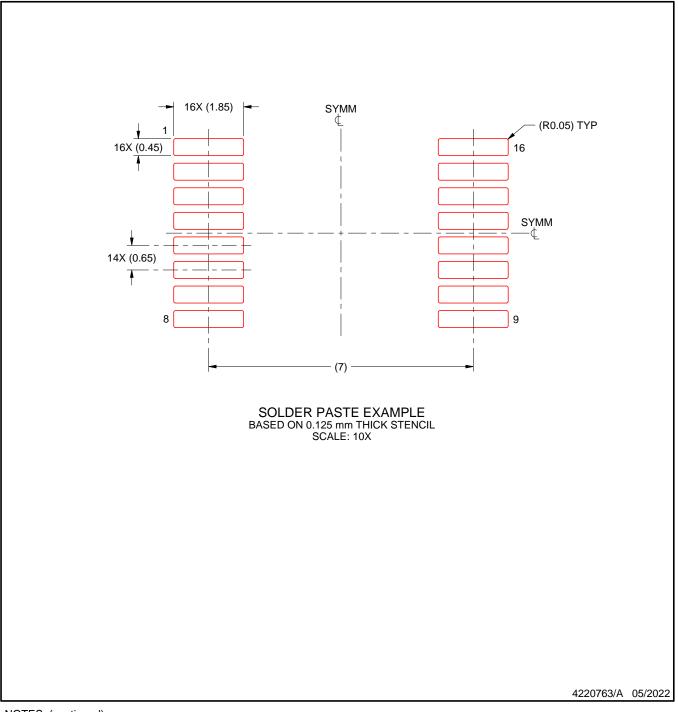


# DB0016A

# **EXAMPLE STENCIL DESIGN**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



<sup>7.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

### MECHANICAL DATA

### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



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